INTEGRATED CIRCUITS



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**Philips Semiconductors** 





## FEATURES

- External clock frequency 30 to 80 kHz (typ. 38.4 kHz)
- Supported data rates 600, 1200, 2400 and 4800 bits/s (typ.)
- Double bandwidth option (not for 4800 bits/s)
- · Schmitt-triggered inputs for optimum slope tolerance
- Enable input for power-down mode
- Open-drain output (3-state in power-down mode)
- No external components required
- Single supply voltage from 1.8 to 6.0 V
- Very low operating current (1.5 μA typ.)
- Operating temperature from -10 to +70 °C.

## APPLICATIONS

- Telemetry data receivers
- RF security systems
- Low-bit-rate radio data links
- Paging applications of UAA2080 and UAA2082 with software decoding.

#### QUICK REFERENCE DATA

## GENERAL DESCRIPTION

The OM4031T is intended for performance enhancement of FSK data receivers that do not have a built-in post-detection filter.

It contains a digital moving average filter to remove noise from the demodulated data. When operated from a 38.4 kHz external clock it can handle data rates of 600, 1200 and 2400 bits/s at an oversampling rate of 16. The filter bandwidth can be doubled to ease the search for bit synchronization on the output data.

To allow for jitter in the input data, a 12-bit sample is taken for the majority decision. Doubling the filter bandwidth is realised by taking the majority out of 6 samples (2400 bits/s) or by doubling the sampling rate (600 and 1200 bits/s).

An input data rate of 4800 bits/s is supported at 8 times oversampling and normal bandwidth.

All inputs are Schmitt-triggered to ensure reliable operation even at signals with long rise/fall times.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>DD</sub>	supply voltage		1.8	-	6.0	V
I <sub>DDPD</sub>	power-down supply current	$CE = V_{SS}$	-	1.0	10.0	μA
I <sub>DD</sub>	operating supply current	CE = V <sub>DD</sub> ; note 1	_	1.5	20.0	μA
P <sub>i(ref)</sub>	sensitivity improvement at 3% bit error rate	note 2				
		600 bits/s, 250 μs slope	-	5.3	-	dB
		1200 bits/s, 250 μs slope	-	3.6	-	dB
		2400 bits/s, 125 μs slope	_	2.0	-	dB
T <sub>amb</sub>	operating ambient temperature		-10	-	+70	°C

#### Notes

- 1. V<sub>DD</sub> = 2.0 V; DOUT open-circuit; input data at 20 kHz random pattern.
- 2. Bench evaluated for UAA2080H at 470 MHz, not factory tested.

#### **ORDERING INFORMATION**

		PACKAGE				
	NAME	DESCRIPTION	VERSION			
OM4031T	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1			

OM4031T

# Digital post-detection filter for FSK data receivers

## BLOCK DIAGRAM



## PINNING

SYMBOL	PIN	DESCRIPTION	
DIN	1	data input	
CE	2	chip enable input	
CLK	3	external clock input	
V <sub>SS</sub>	4	negative supply voltage	
DOUT	5	data output (open-drain)	
A0	6	data rate and bandwidth control input 0 (see Table 1)	
A1	7	data rate and bandwidth control input 1 (see Table 1)	
V <sub>DD</sub>	8	positive supply voltage	



The OM4031T digital post-detection filter oversamples the noisy binary data stream at input DIN (pin 1), and outputs a noise-reduced data stream via open-drain output DOUT (pin 5). The filter bandwidth can be doubled to ease the search for bit synchronization on the data output signal.

Input sampling takes place at 16 times the data rate. For a typical clock frequency of 38.4 kHz the nominal data rates are 600, 1200 and 2400 bits/s. A data rate of 4800 bits/s can be handled at an oversampling rate of 8 and at normal bandwidth only.

Using a different clock frequency will produce bit rates equal to the clock frequency divided by 64, 32 or 16. When the clock frequency is not an integer multiple of the data rate some edge jitter will be introduced in the output data.

The clock frequency is not very critical for the noise filtering performance: a clock frequency of 32.768 kHz could be used at 512, 1200 and 2400 bits/s without loss of performance.

Since no on-chip oscillator is available an external clock signal is required at input CLK (pin 3). Two control inputs A0 and A1 (pins 6 and 7) are used for selection of the data rate and the filter bandwidth.

A separate enable input CE (pin 2) allows the circuit to be powered down. In power-down mode (CE = LOW) the system clock is inhibited and the data output DOUT is made 3-state and remains static.

#### Moving average noise filter

Noise reduction is achieved by applying a moving average filter on N samples of the input data signal. In principle N can be odd or even, but in the OM4031T an even number is used (N = 12). When there is no absolute majority (equal number of ones and zeroes) the previous majority output is maintained.

An odd value for N would always produce an absolute majority and not require decision feedback. However the noise performance is worse for odd values of N, because the output can toggle at every clock (e.g. when a 101010... pattern is clocked in). For even values of N the output polarity can only change once every 3 clocks and does not toggle at all for a 101010... or a 11001100... pattern.

Using 12 out of 16 samples for the majority decision produces a filter which combines good noise reduction with a large tolerance for data jitter (maximum  $\frac{1}{8}$ -bit duration).

#### Filter implementation

The moving average filter is implemented using a 13-bit register and two state machines (COUNT and CLOCK) for the majority decision. The first stage of the shift register is used for input synchronization.

The CLOCK state machine generates the internal clock signal CINT and the bandwidth selection signal DBW in accordance with the logic levels on control lines CE, A0 and A1.

The majority decision is taken by state machine COUNT based on the contents of the input shift register and the previous decision in the output latch.

The doubled bandwidth is achieved by increasing the sampling rate by a factor of 2 for 600 and 1200 bits/s. For 2400 bits/s the number of samples for the majority decision is halved, controlled by the DBW signal. This signal is derived from the control signals as follows:

$$\mathsf{DBW} = \mathsf{CE} \bullet \mathsf{A0} \bullet \overline{\mathsf{A1}}$$

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### Filter characteristic

The frequency characteristic of the moving average filter in the OM4031T is given in Fig.3 for N = 12 and N = 6.

The horizontal axis shows the normalized frequency  $f_N$  which is the ratio of the frequency f and the sampling frequency  $f_s$ . The value for  $f_s$  is given in Table 1 for the various data rates and filter bandwidths.

The vertical axis shows the normalized amplitude A<sub>N</sub>.

At normal bandwidth the oversampling rate is 16, except for 4800 bits/s where it is 8. At double bandwidth the oversampling rate is 32, except for 2400 bits/s, where it is 16.

The 3 dB cut-off frequency is calculated as follows:

N = 12: 
$$f_{co} = 0.0371 \times f_{s}$$

N = 6: 
$$f_{co} = 0.0748 \times f_{s}$$



#### **Noise reduction**

The performance of the OM4031T was bench tested by measuring the sensitivity improvement (3% BER) of the UAA2080H pager receiver at various bit rates using a stand-alone pager receiver board (OM4647 at 470 MHz). The results are given in Chapter "AC Characteristics".

The OM4031T was also tested in a POCSAG pager application using software decoding together with the UAA2080H receiver.

For 12-digit numeric messages at 1200 bits/s the typical sensitivity for 80% call success rate improved by 2.8 dB, as shown in Fig.4.



## OM4031T

## **OPERATING INSTRUCTIONS**

### Control signals

The operation of the OM4031T is determined by 3 control signals (CE, A0 and A1) and the clock frequency at input CLK. Table 1 shows the various possibilities for a typical clock frequency of 38.4 kHz.

The parameter N is the number of samples used in the calculation of the average bit value.

The parameter  $f_{\text{s}}$  is the input sampling frequency, assuming a 38.4 kHz external clock signal.

The logic levels on A0 and A1 can be changed while CE = HIGH, except to select or deselect 2400 bits/s with doubled bandwidth (A1 = LOW, A0 = HIGH). This mode must be entered or left while CE = LOW to avoid data errors on DOUT.

			N	<i>.</i>	DATA RATE (bits/s)		
CE	A1	A0	(samples)	(kHz)	NORMAL BANDWIDTH	DOUBLE BANDWIDTH	
0	Х	Х	Х	Х	Х	Х	
1	0	0	12	9.6	600	_	
1	1	0	12	19.2	1200	600	
1	0	1	6	38.4	4800 <sup>(1)</sup>	2400	
1	1	1	12	38.4	2400	1200	

#### Table 1 Data rate and filter bandwidth selection

#### Note

1. At 4800 bits/s the oversampling rate is 8.

### Power-down mode

To reduce power consumption the filter can be disabled by applying a LOW level to input CE. The result is as follows:

- The internal clock is inhibited
- Output DOUT is made 3-state and static.

#### Reset

The OM4031T is reset internally when power-down mode is left by applying a HIGH level to input CE. The actual reset takes place on the second falling edge on input CLK after CE = HIGH. The status after reset is as follows:

- The shift register contains a 101010... pattern
- DOUT is made LOW.

After power-up input CE must be kept at a LOW level for at least one clock period on input CLK. This ensures a successful reset when CE is made HIGH.

## OM4031T

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>DD</sub>	supply voltage	-0.5	7.0	V
VI	input voltage on any pin	-0.5	V <sub>DD</sub> + 0.5	V
I <sub>I</sub>	DC input current all pins	_	20	mA
I <sub>O</sub>	DC output current all pins	_	20	mA
P <sub>tot</sub>	total power dissipation		150	mW
T <sub>amb</sub>	operating ambient temperature	-10	+70	°C
T <sub>stg</sub>	storage temperature	-55	+125	°C

## DC CHARACTERISTICS

 $V_{DD}$  = 1.8 to 6.0 V;  $V_{SS}$  = 0 V;  $T_{amb}$  = -10 to +70 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supplies						•
V <sub>DD</sub>	supply voltage		1.8	-	6.0	V
I <sub>DDPD</sub>	power-down supply voltage	CE = V <sub>SS</sub> ; note 1	-	1.0	10.0	μA
I <sub>DD</sub>	operating supply current	$CE = V_{DD}$ ; notes 1 and 2	-	1.5	20.0	μA
Inputs A0, A1,	Inputs A0, A1, CLK and CE					
V <sub>IL</sub>	LOW level input voltage		-0.5	-	+0.3V <sub>DD</sub>	V
V <sub>IH</sub>	HIGH level input voltage		0.7V <sub>DD</sub>	_	V <sub>DD</sub> + 0.5	V
ILI	input leakage current	$V_I = V_{DD}$ or $V_I = V_{SS}$	-	_	1.0	μA
Cl	input capacitance	tested on sample basis	-	2.0	_	pF
Output DOUT						
I <sub>OL</sub>	LOW level output current	V <sub>OL</sub> = 0.4 V	1.0	_	_	mA
I <sub>LO</sub>	output leakage current	$V_{OH} = V_{DD}$	-	-	1.0	μA

## Notes

1.  $V_{DD} = 2.0 \text{ V}$ ;  $V_{IL} = V_{SS}$ ;  $V_{IH} = V_{DD}$ ; DOUT is open-circuit; clock signal at input CLK;  $f_{clk} = 38.4 \text{ kHz}$ , amplitude:  $V_{SS}$  to  $V_{DD}$ ; data signal at input DIN: random pattern at 20 kHz to simulate 2400 bits/s data with noise;  $t_r = t_f = 5 \text{ ns}$ .

 The operating current will be higher than specified when the input signal amplitude is less than 100% (equals V<sub>SS</sub> to V<sub>DD</sub>) or when longer rise/fall times are used. This is caused by the Schmitt-trigger circuits drawing extra current.

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## AC CHARACTERISTICS

 $V_{DD}$  = 1.8 to 6.0 V;  $V_{SS}$  = 0 V;  $T_{amb}$  = -10 to +70 °C;  $f_{clk}$  = 38.4 kHz; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
External c	External clock					
f <sub>clk</sub>	external clock frequency		30	38.4	80	kHz
Filter bane	dwidth (note 1)					
f <sub>co</sub>	cut-off frequency (-3 dB)	normal bandwidth				
		600 bits/s	-	356	-	Hz
		1200 bits/s	-	712	-	Hz
		2400 bits/s	-	1425	-	Hz
		4800 bits/s	-	2872	-	Hz
		double bandwidth				
		600 bits/s	-	712	-	Hz
		1200 bits/s	-	1425	-	Hz
		2400 bits/s	-	2872	-	Hz
Noise reduction (note 2)						
P <sub>i(ref)</sub>	sensitivity improvement at 3% bit error rate	note 3				
		600 bits/s, 250 μs slope	-	5.3	-	dB
		1200 bits/s, 250 μs slope	-	3.6	-	dB
		2400 bits/s, 125 μs slope	-	2.0	-	dB

#### Notes

1. Filter bandwidth is guaranteed by design. Values supplied are simulation results.

2. Noise reduction is not factory tested, only bench evaluated.

3. Sensitivity improvement was bench tested on the UAA2080H demonstration board OM4747. Test signal: preamble (101010...),  $f_{iRF} = 469.950$  MHz, deviation = ±4.0 kHz, slope = 10 to 90% of amplitude,  $V_P = 2.05$  V,  $T_{amb} = 25$  °C. See "UAA2080 data sheet, AC characteristics".

### **APPLICATION INFORMATION**



The OM4031T will generally operate from the same power supply ( $V_{CC}$ ) as the FSK data receiver providing its input data. The open-drain data output allows level shifting of the data to suit a microcontroller operating at a higher power supply voltage ( $V_{DD}$ ).

The value of the pull-up resistor  $R_{pull}$  on output DOUT is determined by the type and number of input circuits to be driven. The required signal rise time must be balanced against the current drawn by the pull-up.

For the highest rate (2400 bits/s) the signal rise time should preferably be below 50  $\mu$ s.

For a single CMOS input with a 10 pF capacitance  $R_{pull}$  = 1  $M\Omega$  gives a rise time of approximately 30  $\mu s$  (3  $\times$  t<sub>RC</sub>). At V<sub>DD</sub> = 2.0 V this corresponds with a current of 2  $\mu A$ .

## OM4031T

## PACKAGE OUTLINE



## SOLDERING

#### Plastic small-outline packages

BY WAVE

During placement and before soldering, the component must be fixed with a droplet of adhesive. After curing the adhesive, the component can be soldered. The adhesive can be applied by screen printing, pin transfer or syringe dispensing.

Maximum permissible solder temperature is 260  $^{\circ}$ C, and maximum duration of package immersion in solder bath is 10 s, if allowed to cool to less than 150  $^{\circ}$ C within 6 s. Typical dwell time is 4 s at 250  $^{\circ}$ C.

A modified wave soldering technique is recommended using two solder waves (dual-wave), in which a turbulent wave with high upward pressure is followed by a smooth laminar wave. Using a mildly-activated flux eliminates the need for removal of corrosive residues in most applications.

#### BY SOLDER PASTE REFLOW

Reflow soldering requires the solder paste (a suspension of fine solder particles, flux and binding agent) to be

applied to the substrate by screen printing, stencilling or pressure-syringe dispensing before device placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt, infrared, and vapour-phase reflow. Dwell times vary between 50 and 300 s according to method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 min at 45 °C.

REPAIRING SOLDERED JOINTS (BY HAND-HELD SOLDERING IRON OR PULSE-HEATED SOLDER TOOL)

Fix the component by first soldering two, diagonally opposite, end pins. Apply the heating tool to the flat part of the pin only. Contact time must be limited to 10 s at up to  $300 \,^{\circ}$ C. When using proper tools, all other pins can be soldered in one operation within 2 to 5 s at between 270 and 320  $^{\circ}$ C. (Pulse-heated soldering is not recommended for SO packages.)

For pulse-heated solder tool (resistance) soldering of VSO packages, solder is applied to the substrate by dipping or by an extra thick tin/lead plating before package placement.

## DEFINITIONS

Data sheet status					
Objective specification This data sheet contains target or goal specifications for product development.					
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification This data sheet contains final product specifications.					
Limiting values					
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.					
Annulisation information					

## Application information

Where application information is given, it is advisory and does not form part of the specification.

### LIFE SUPPORT APPLICATIONS

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## Philips Semiconductors – a worldwide company

Argentina: IEROD, Av. Juramento 1992 - 14.b, (1428) BUENOS AIRES, Tel. (541)786 7633, Fax. (541)786 9367 Australia: 34 Waterloo Road, NORTH RYDE, NSW 2113, Tel. (02)805 4455, Fax. (02)805 4466 Austria: Triester Str. 64, A-1101 WIEN, P.O. Box 213, Tel. (01)60 101-1236, Fax. (01)60 101-1211 Belgium: Postbus 90050, 5600 PB EINDHOVEN, The Netherlands, Tel. (31)40 783 749, Fax. (31)40 788 399 Brazil: Rua do Rocio 220 - 5<sup>th</sup> floor, Suite 51, CEP: 04552-903-SÃO PAULO-SP, Brazil. P.O. Box 7383 (01064-970) Tel. (011)821-2333, Fax. (011)829-1849 Canada: PHILIPS SEMICONDUCTORS/COMPONENTS: Tel. (800) 234-7381, Fax. (708) 296-8556 Chile: Av. Santa Maria 0760, SANTIAGO, Tel. (02)773 816, Fax. (02)777 6730 Colombia: IPRELENSO LTDA, Carrera 21 No. 56-17, 77621 BOGOTA, Tel. (571)249 7624/(571)217 4609, Fax. (571)217 4549 Denmark: Prags Boulevard 80, PB 1919, DK-2300 COPENHAGEN S, Tel. (032)88 2636, Fax. (031)57 1949 Finland: Sinikalliontie 3, FIN-02630 ESPOO, Tel. (9)0-50261, Fax. (9)0-520971 France: 4 Rue du Port-aux-Vins, BP317, 92156 SURESNES Cedex, Tel. (01)4099 6161, Fax. (01)4099 6427 Germany: P.O. Box 10 63 23, 20043 HAMBURG, Tel. (040)3296-0, Fax. (040)3296 213. Greece: No. 15, 25th March Street, GR 17778 TAVROS, Tel. (01)4894 339/4894 911, Fax. (01)4814 240 Hong Kong: PHILIPS HONG KONG Ltd., 6/F Philips Ind. Bldg., 24-28 Kung Yip St., KWAI CHUNG, N.T., Tel. (852)424 5121, Fax. (852)428 6729 India: Philips INDIA Ltd, Shivsagar Estate, A Block , Dr. Annie Besant Rd. Worli, Bombay 400 018 Tel. (022)4938 541, Fax. (022)4938 722 Indonesia: Philips House, Jalan H.R. Rasuna Said Kav. 3-4, P.O. Box 4252, JAKARTA 12950, Tel. (021)5201 122, Fax. (021)5205 189 Ireland: Newstead, Clonskeagh, DUBLIN 14, Tel. (01)640 000, Fax. (01)640 200 Italy: PHILIPS SEMICONDUCTORS S.r.I. Piazza IV Novembre 3, 20124 MILANO Tel. (0039)2 6752 2531, Fax. (0039)2 6752 2557 Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku, TOKYO 108, Tel. (03)3740 5028, Fax. (03)3740 0580 Korea: (Republic of) Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL, Tel. (02)794-5011, Fax. (02)798-8022 Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR, Tel. (03)750 5214, Fax. (03)757 4880 Mexico: 5900 Gateway East, Suite 200, EL PASO, TX 79905, Tel. 9-5(800)234-7381, Fax. (708)296-8556 Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB Tel. (040)783749, Fax. (040)788399 New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND, Tel. (09)849-4160, Fax. (09)849-7811 Norway: Box 1, Manglerud 0612, OSLO, Tel. (022)74 8000, Fax. (022)74 8341

Pakistan: Philips Electrical Industries of Pakistan Ltd., Exchange Bldg. ST-2/A, Block 9, KDA Scheme 5, Clifton, KARACHI 75600, Tel. (021)587 4641-49, Fax. (021)577035/5874546. Philippines: PHILIPS SEMICONDUCTORS PHILIPPINES Inc, 106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI, Metro MANILA, Tel. (02)810 0161, Fax. (02)817 3474 Portugal: PHILIPS PORTUGUESA, S.A. Rua dr. António Loureiro Borges 5, Arquiparque - Miraflores, Apartado 300, 2795 LINDA-A-VELHA, Tel. (01)4163160/4163333, Fax. (01)4163174/4163366. Singapore: Lorong 1, Toa Payoh, SINGAPORE 1231, Tel. (65)350 2000, Fax. (65)251 6500 South Africa: S.A. PHILIPS Pty Ltd. 195-215 Main Road Martindale, 2092 JOHANNESBURG, P.O. Box 7430 Johannesburg 2000, Tel. (011)470-5911, Fax. (011)470-5494. Spain: Balmes 22, 08007 BARCELONA, Tel. (03)301 6312, Fax. (03)301 42 43 Sweden: Kottbygatan 7, Akalla. S-164 85 STOCKHOLM, Tel. (0)8-632 2000, Fax. (0)8-632 2745 Switzerland: Allmendstrasse 140, CH-8027 ZÜRICH, Tel. (01)488 2211, Fax. (01)481 77 30 Taiwan: PHILIPS TAIWAN Ltd., 23-30F, 66, Chung Hsiao West Road, Sec. 1. Taipeh, Taiwan ROC, P.O. Box 22978, TAIPEI 100, Tel. (02)388 7666, Fax. (02)382 4382. Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd., 209/2 Sanpavuth-Bangna Road Prakanong, Bangkok 10260, THAILAND, Tel. (662)398-0141, Fax. (662)398-3319. Turkey: Talatpasa Cad. No. 5, 80640 GÜLTEPE/ISTANBUL, Tel. (0212)279 2770, Fax. (0212)269 3094 United Kingdom: Philips Semiconductors LTD. 276 Bath road, Hayes, MIDDLESEX UB3 5BX, Tel. (081)73050000, Fax. (081)7548421 United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409, Tel. (800)234-7381, Fax. (708)296-8556 Uruguay: Coronel Mora 433, MONTEVIDEO, Tel. (02)70-4044, Fax. (02)92 0601

For all other countries apply to: Philips Semiconductors, International Marketing and Sales, Building BE-p, P.O. Box 218, 5600 MD, EINDHOVEN, The Netherlands, Telex 35000 phtcnl, Fax. +31-40-724825

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